Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

TAIWAN SEMICONDUCTOR

RoHS COMPLIANCE

TSM2323

20V P-Channel MOSFET

SOT-23

Pin Definition:
1. Gate
2. Source
3. Drain

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$(mΩ)	I_D (A)
-20	39 @ V_{GS} = -4.5V	-4.7
	52 @ V_{GS} = -2.5V	-4.1
	68 @ V_{GS} = -1.8V	-2.0

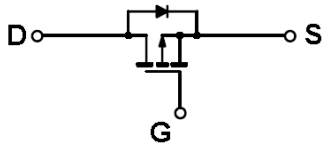
Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PA Switch

Block Diagram



P-Channel MOSFET

Ordering Information

Part No.	Package	Packing
TSM2323CX RFG	SOT-23	3Kpcs / 7" Reel

Note: "G" denote for Green Product

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±8	V
Continuous Drain Current, V_{GS} @ 4.5V.		I_D	-4.7	A
Pulsed Drain Current, V_{GS} @ 4.5V		I_{DM}	-20	A
Continuous Source Current (Diode Conduction)[a,b]		I_S	-1.0	A
Maximum Power Dissipation	Ta = 25°C	P_D	1.25	W
	Ta = 70°C		0.8	
Operating Junction Temperature		T_J	+150	°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Case Thermal Resistance	$R\Theta_{JC}$	75	°C/W
Junction to Ambient Thermal Resistance (PCB mounted)	$R\Theta_{JA}$	120	°C/W

Notes:

a. Surface Mounted on 1" x 1" FR4 Board.

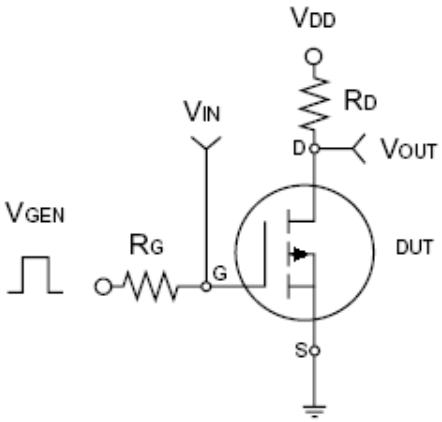
b. Pulse width limited by maximum junction temperature

TSM2323
20V P-Channel MOSFET

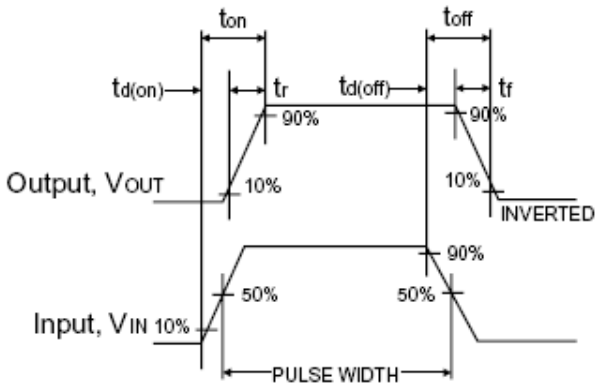
Electrical Specifications

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	V_{GS} = 0V, I_D = - 250uA	BV_{DSS}	-20	--	--	V
Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = - 250uA	$V_{GS(TH)}$	-0.4	--	-1.0	V
Zero Gate Voltage Drain Current	V_{DS} = -16V, V_{GS} = 0V	I_{DSS}	--	--	-1.0	uA
Gate Body Leakage	V_{GS} = ±8V, V_{DS} = 0V	I_{GSS}	--	--	±100	nA
On-State Drain Current	V_{DS} ≤-5V, V_{GS} = -4.5V	$I_{D(ON)}$	-20	--	--	A
Drain-Source On-State Resistance	V_{GS} = -4.5V, I_D = -4.7A	$R_{DS(ON)}$	--	31	39	mΩ
	V_{GS} = -2.5V, I_D = -4.1A		--	41	52	
	V_{GS} = -1.8V, I_D = -2.0A		--	54	68	
Forward Transconductance	V_{DS} = - 5V, I_D = - 4.7A	g_{fs}	--	16	--	S
Diode Forward Voltage	I_S = - 1.0A, V_{GS} = 0V	V_{SD}	--	- 0.7	-1.2	V
Dynamic[b]						
Total Gate Charge	V_{DS} = -10V, I_D = -4.7A, V_{GS} = -4.5V	Q_g	--	12.5	19	nC
Gate-Source Charge		Q_{gs}	--	1.7	--	
Gate-Drain Charge		Q_{gd}	--	3.3	--	
Input Capacitance	V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz	C_{iss}	--	1020	--	pF
Output Capacitance		C_{oss}	--	191	--	
Reverse Transfer Capacitance		C_{rss}	--	140	--	
Switching[b,c]						
Turn-On Delay Time	V_{DD} = -10V, R_L = 10Ω, I_D = -1A, V_{GEN} = -4.5V, R_G = 6Ω	$t_{d(on)}$	--	25	40	nS
Turn-On Rise Time		t_r	--	43	65	
Turn-Off Delay Time		$t_{d(off)}$	--	71	110	
Turn-Off Fall Time		t_f	--	48	75	

Notes:
a. pulse test: PW ≤ 300μS, duty cycle ≤ 2%
b. Guaranteed by design of component.
c. Switching time is essentially independent of operating temperature.



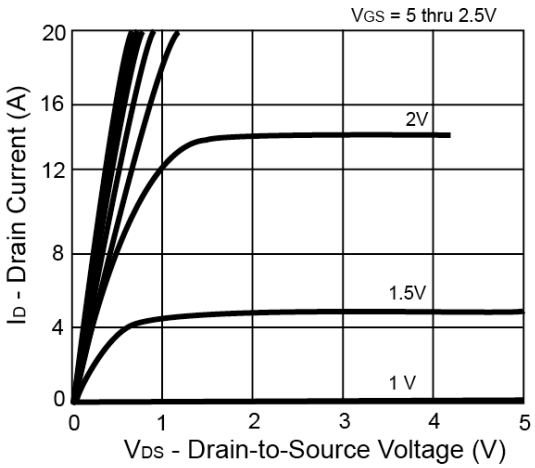
Switching Test Circuit



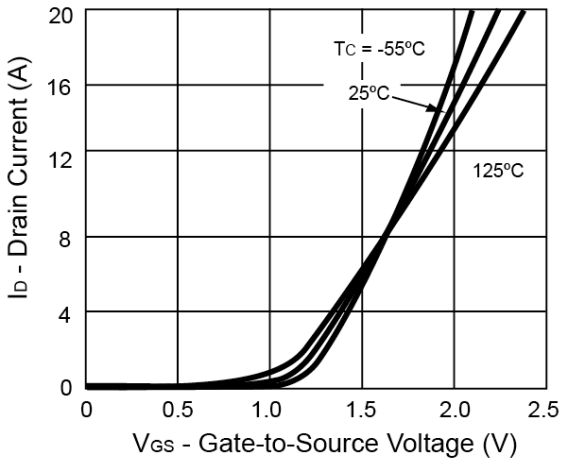
Switchin Waveforms

Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

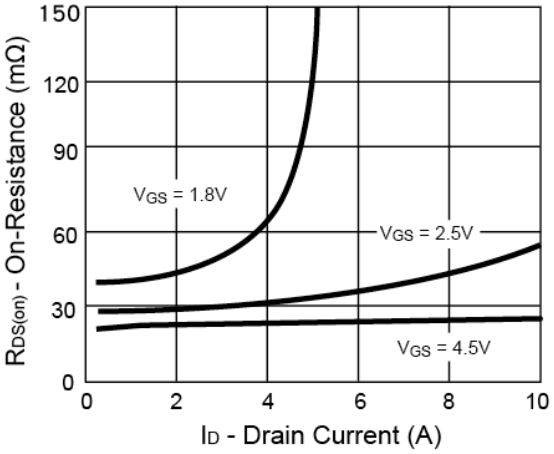
Output Characteristics



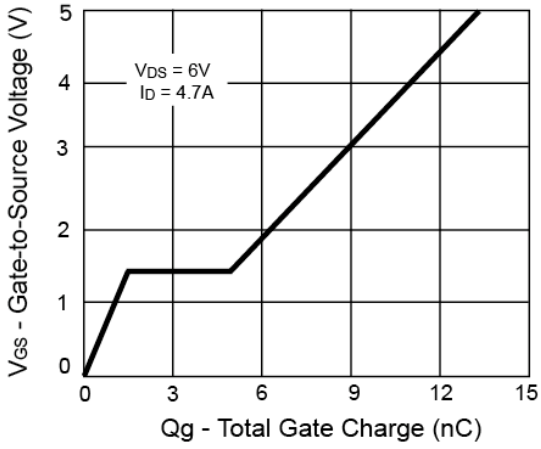
Transfer Characteristics



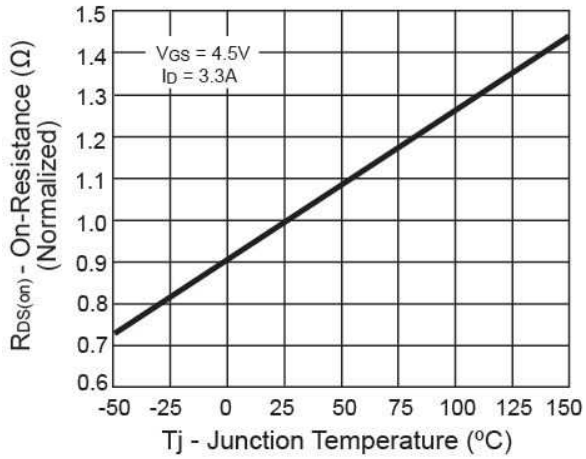
On-Resistance vs. Drain Current



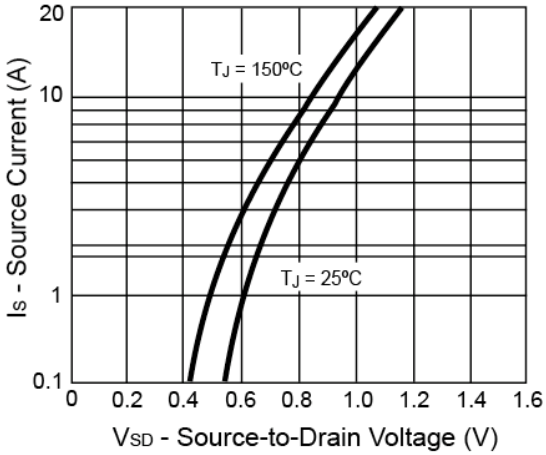
Gate Charge



On-Resistance vs. Junction Temperature

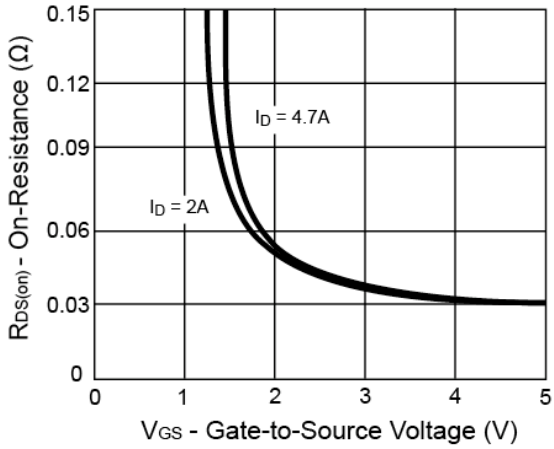


Source-Drain Diode Forward Voltage

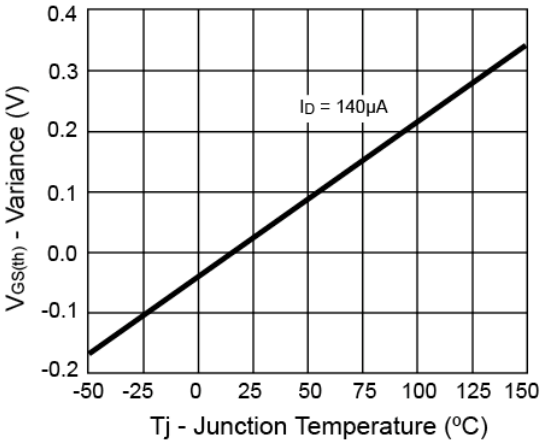


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

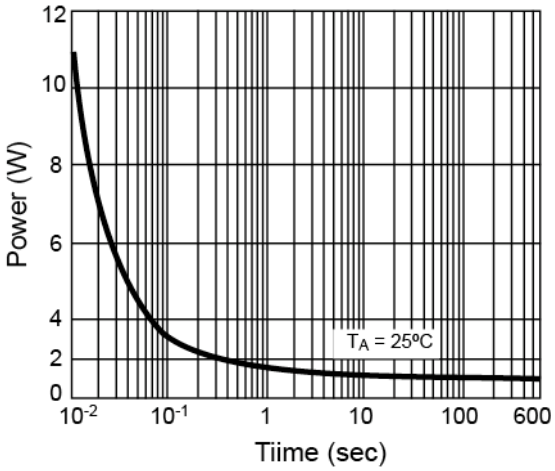
On-Resistance vs. Gate-Source Voltage



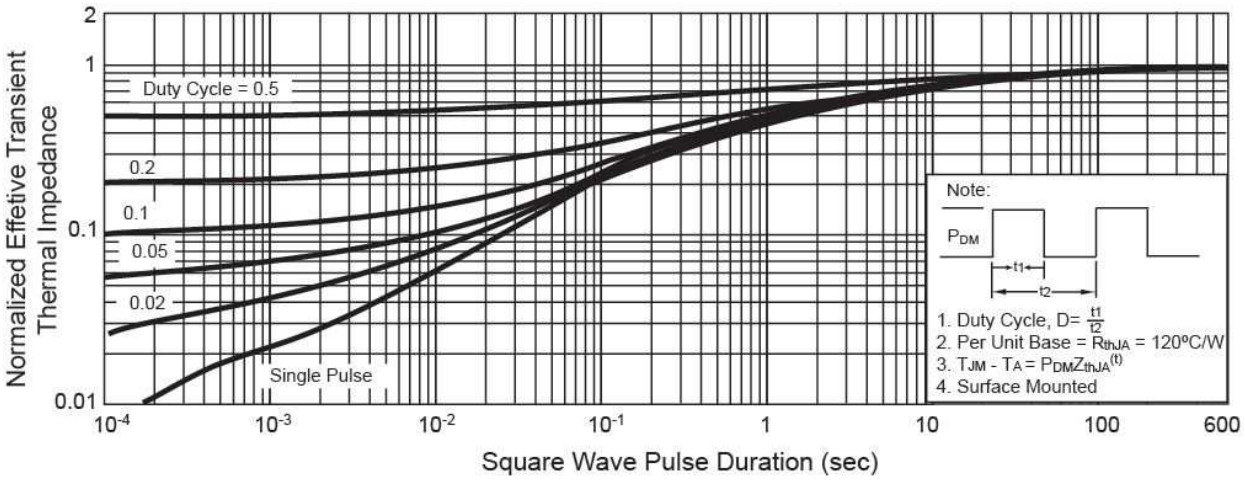
Threshold Voltage



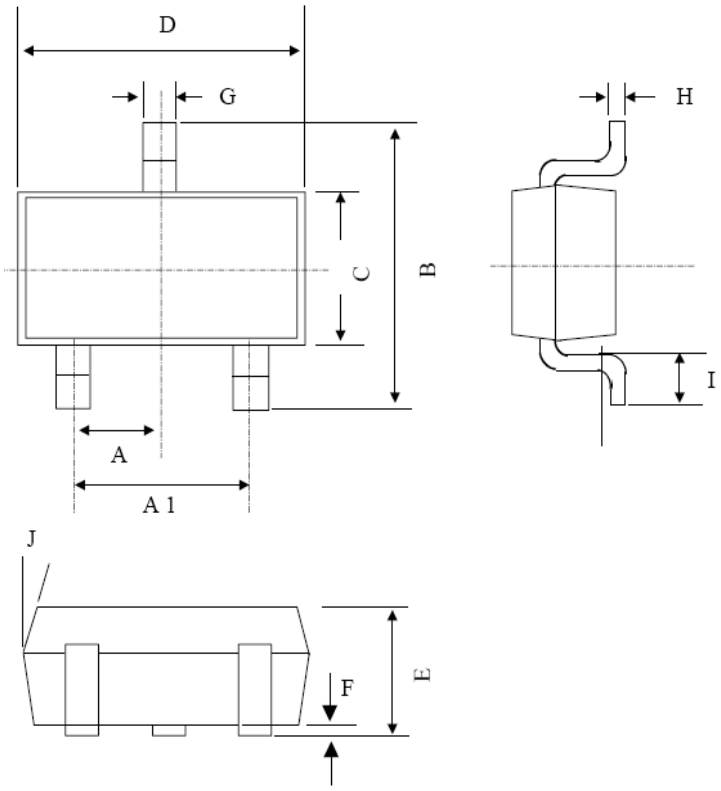
Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

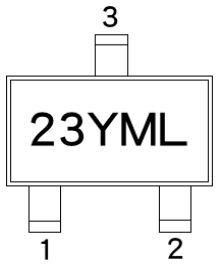


SOT-23 Mechanical Drawing



SOT-23 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX.
A	0.95 BSC		0.037 BSC	
A1	1.9 BSC		0.074 BSC	
B	2.60	3.00	0.102	0.118
C	1.40	1.70	0.055	0.067
D	2.80	3.10	0.110	0.122
E	1.00	1.30	0.039	0.051
F	0.00	0.10	0.000	0.004
G	0.35	0.50	0.014	0.020
H	0.10	0.20	0.004	0.008
I	0.30	0.60	0.012	0.024
J	5º	10º	5º	10º

Marking Diagram



23 = Device Code
Y = Year Code
M = Month Code for Halogen Free Product

O	=Jan	**P**	=Feb	**Q**	=Mar	**R**	=Apr
S	=May	**T**	=Jun	**U**	=Jul	**V**	=Aug
W	=Sep	**X**	=Oct	**Y**	=Nov	**Z**	=Dec

L = Lot Code

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.